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### Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### Details

Product Status	Obsolete
Number of LABs/CLBs	360
Number of Logic Elements/Cells	2880
Total RAM Bits	40960
Number of I/O	102
Number of Gates	199000
Voltage - Supply	2.3V ~ 2.7V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 85°C (TA)
Package / Case	144-LQFP
Supplier Device Package	144-TQFP (20x20)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/intel/epf10k50eti144-2">https://www.e-xfl.com/product-detail/intel/epf10k50eti144-2</a>

- Software design support and automatic place-and-route provided by Altera's development systems for Windows-based PCs and Sun SPARCstation, and HP 9000 Series 700/800
- Flexible package options
  - Available in a variety of packages with 144 to 672 pins, including the innovative FineLine BGA™ packages (see [Tables 3 and 4](#))
  - SameFrame™ pin-out compatibility between FLEX 10KA and FLEX 10KE devices across a range of device densities and pin counts
- Additional design entry and simulation support provided by EDIF 2.0.0 and 3.0.0 netlist files, library of parameterized modules (LPM), DesignWare components, Verilog HDL, VHDL, and other interfaces to popular EDA tools from manufacturers such as Cadence, Exemplar Logic, Mentor Graphics, OrCAD, Synopsys, Synplcity, VeriBest, and Viewlogic

**Table 3. FLEX 10KE Package Options & I/O Pin Count** *Notes (1), (2)*

Device	144-Pin TQFP	208-Pin PQFP	240-Pin PQFP RQFP	256-Pin FineLine BGA	356-Pin BGA	484-Pin FineLine BGA	599-Pin PGA	600-Pin BGA	672-Pin FineLine BGA
EPF10K30E	102	147		176		220			220 (3)
EPF10K50E	102	147	189	191		254			254 (3)
EPF10K50S	102	147	189	191	220	254			254 (3)
EPF10K100E		147	189	191	274	338			338 (3)
EPF10K130E			186		274	369		424	413
EPF10K200E							470	470	470
EPF10K200S			182		274	369	470	470	470

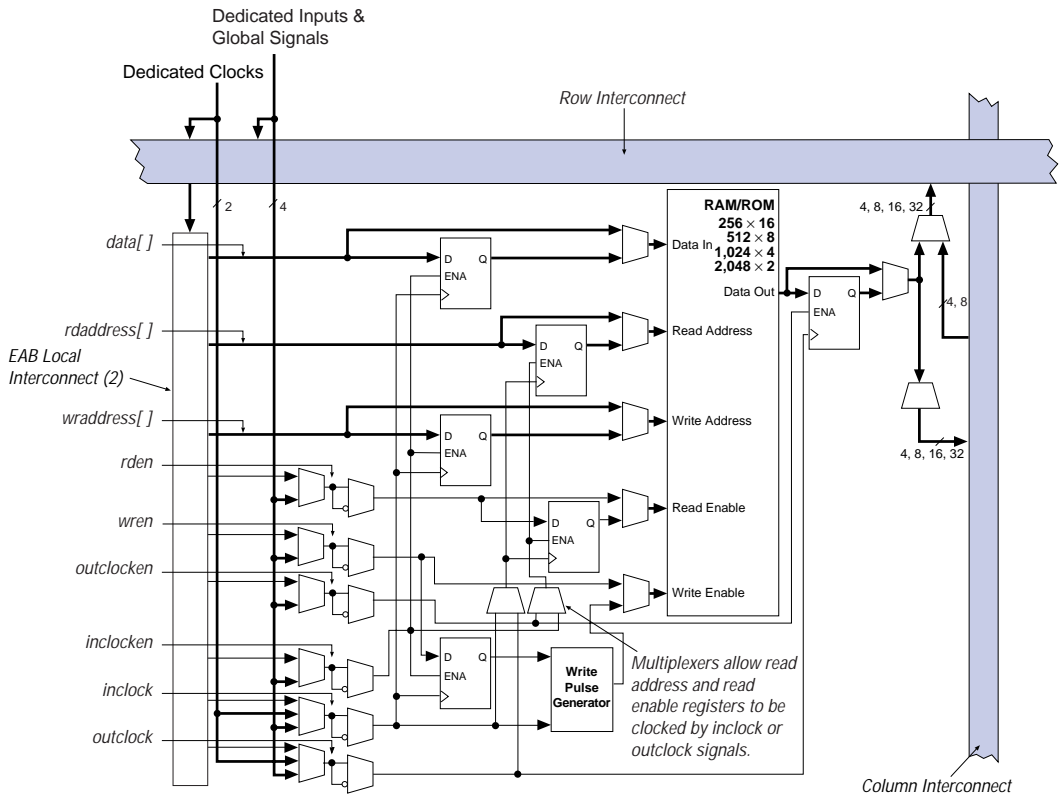
**Notes:**

- (1) FLEX 10KE device package types include thin quad flat pack (TQFP), plastic quad flat pack (PQFP), power quad flat pack (RQFP), pin-grid array (PGA), and ball-grid array (BGA) packages.
- (2) Devices in the same package are pin-compatible, although some devices have more I/O pins than others. When planning device migration, use the I/O pins that are common to all devices.
- (3) This option is supported with a 484-pin FineLine BGA package. By using SameFrame pin migration, all FineLine BGA packages are pin-compatible. For example, a board can be designed to support 256-pin, 484-pin, and 672-pin FineLine BGA packages. The Altera software automatically avoids conflicting pins when future migration is set.

The EAB can also be used for bidirectional, dual-port memory applications where two ports read or write simultaneously. To implement this type of dual-port memory, two EABs are used to support two simultaneous read or writes.

Alternatively, one clock and clock enable can be used to control the input registers of the EAB, while a different clock and clock enable control the output registers (see Figure 2).

Figure 2. FLEX 10KE Device in Dual-Port RAM Mode Notes (1)



**Notes:**

- (1) All registers can be asynchronously cleared by EAB local interconnect signals, global signals, or the chip-wide reset.
- (2) EPF10K30E and EPF10K50E devices have 88 EAB local interconnect channels; EPF10K100E, EPF10K130E, and EPF10K200E devices have 104 EAB local interconnect channels.

*LE Operating Modes*

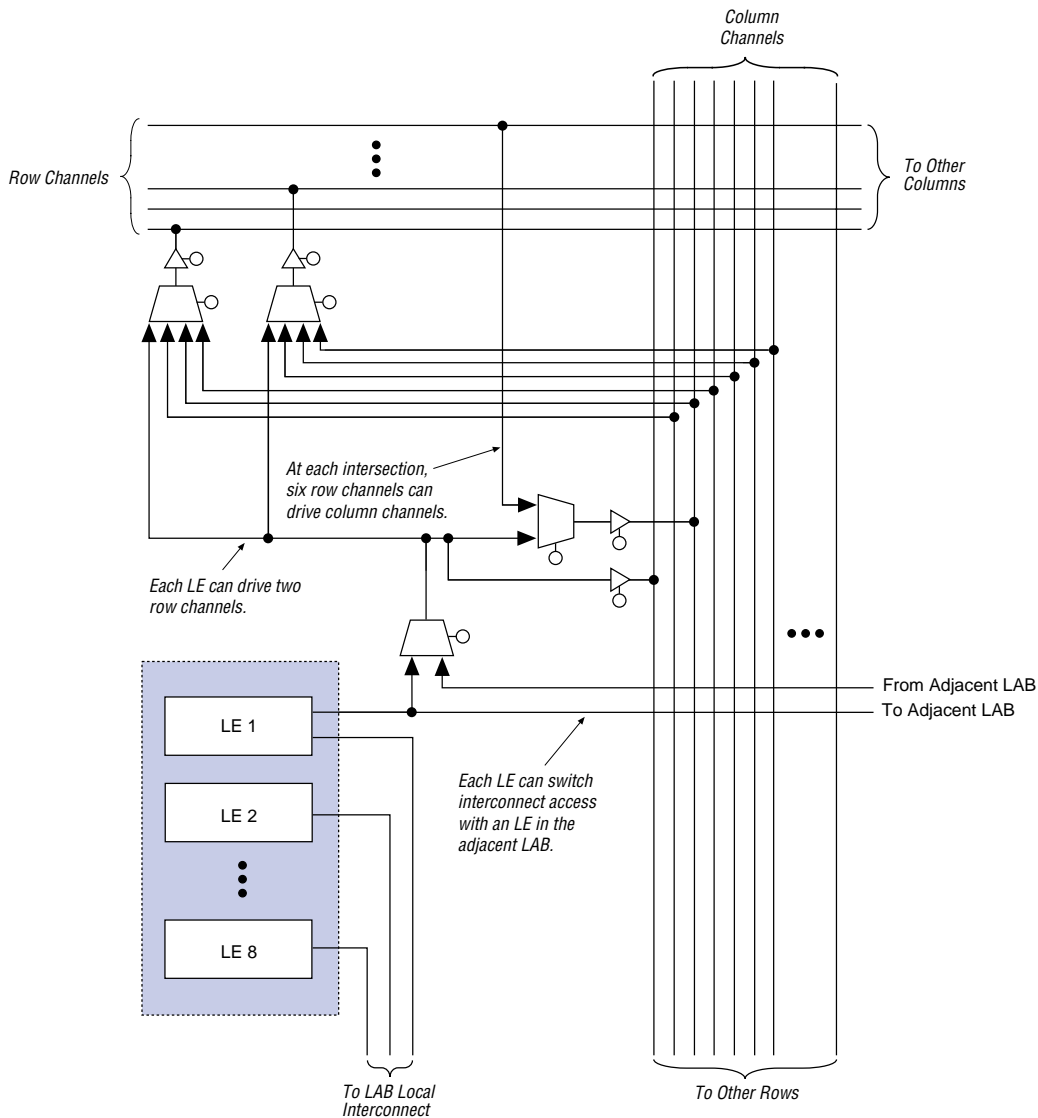
The FLEX 10KE LE can operate in the following four modes:

- Normal mode
- Arithmetic mode
- Up/down counter mode
- Clearable counter mode

Each of these modes uses LE resources differently. In each mode, seven available inputs to the LE—the four data inputs from the LAB local interconnect, the feedback from the programmable register, and the carry-in and cascade-in from the previous LE—are directed to different destinations to implement the desired logic function. Three inputs to the LE provide clock, clear, and preset control for the register. The Altera software, in conjunction with parameterized functions such as LPM and DesignWare functions, automatically chooses the appropriate mode for common functions such as counters, adders, and multipliers. If required, the designer can also create special-purpose functions that use a specific LE operating mode for optimal performance.

The architecture provides a synchronous clock enable to the register in all four modes. The Altera software can set `DATA1` to enable the register synchronously, providing easy implementation of fully synchronous designs.

Figure 13. FLEX 10KE LAB Connections to Row & Column Interconnect

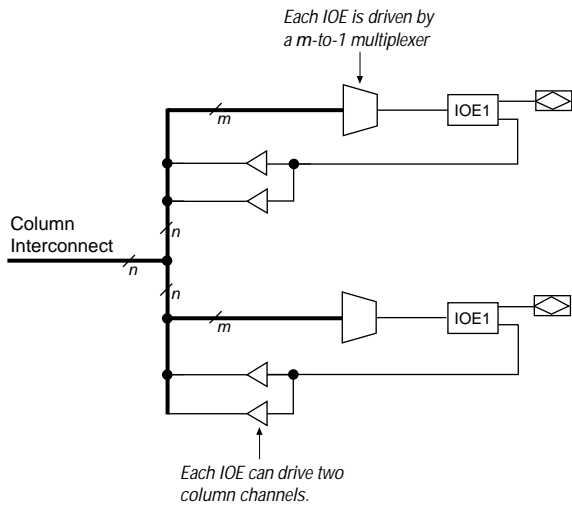


Column-to-IOE Connections

When an IOE is used as an input, it can drive up to two separate column channels. When an IOE is used as an output, the signal is driven by a multiplexer that selects a signal from the column channels. Two IOEs connect to each side of the column channels. Each IOE can be driven by column channels via a multiplexer. The set of column channels is different for each IOE (see [Figure 17](#)).

Figure 17. FLEX 10KE Column-to-IOE Connections

The values for *m* and *n* are provided in [Table 11](#).



[Table 11](#) lists the FLEX 10KE column-to-IOE interconnect resources.

Table 11. FLEX 10KE Column-to-IOE Interconnect Resources		
Device	Channels per Column ( <i>n</i> )	Column Channels per Pin ( <i>m</i> )
EPF10K30E	24	16
EPF10K50E EPF10K50S	24	16
EPF10K100E	24	16
EPF10K130E	32	24
EPF10K200E EPF10K200S	48	40

## ClockLock & ClockBoost Timing Parameters

For the ClockLock and ClockBoost circuitry to function properly, the incoming clock must meet certain requirements. If these specifications are not met, the circuitry may not lock onto the incoming clock, which generates an erroneous clock within the device. The clock generated by the ClockLock and ClockBoost circuitry must also meet certain specifications. If the incoming clock meets these requirements during configuration, the ClockLock and ClockBoost circuitry will lock onto the clock during configuration. The circuit will be ready for use immediately after configuration. Figure 19 shows the incoming and generated clock specifications.

**Figure 19. Specifications for Incoming & Generated Clocks**

The  $t_I$  parameter refers to the nominal input clock period; the  $t_O$  parameter refers to the nominal output clock period.

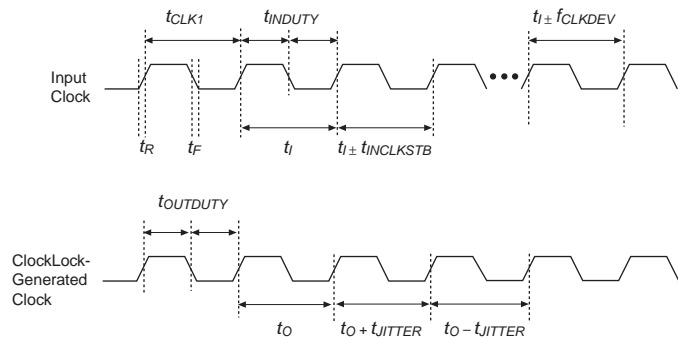


Table 13. ClockLock &amp; ClockBoost Parameters for -2 Speed-Grade Devices

Symbol	Parameter	Condition	Min	Typ	Max	Unit
$t_R$	Input rise time				5	ns
$t_F$	Input fall time				5	ns
$t_{INDUTY}$	Input duty cycle		40		60	%
$f_{CLK1}$	Input clock frequency (ClockBoost clock multiplication factor equals 1)		25		75	MHz
$f_{CLK2}$	Input clock frequency (ClockBoost clock multiplication factor equals 2)		16		37.5	MHz
$f_{CLKDEV}$	Input deviation from user specification in the MAX+PLUS II software (1)				25,000 (2)	PPM
$t_{INCLKSTB}$	Input clock stability (measured between adjacent clocks)				100	ps
$t_{LOCK}$	Time required for ClockLock or ClockBoost to acquire lock (3)				10	μs
$t_{JITTER}$	Jitter on ClockLock or ClockBoost-generated clock (4)	$t_{INCLKSTB} < 100$			250	ps
		$t_{INCLKSTB} < 50$			200 (4)	ps
$t_{OUTDUTY}$	Duty cycle for ClockLock or ClockBoost-generated clock		40	50	60	%

**Notes to tables:**

- (1) To implement the ClockLock and ClockBoost circuitry with the MAX+PLUS II software, designers must specify the input frequency. The Altera software tunes the PLL in the ClockLock and ClockBoost circuitry to this frequency. The  $f_{CLKDEV}$  parameter specifies how much the incoming clock can differ from the specified frequency during device operation. Simulation does not reflect this parameter.
- (2) Twenty-five thousand parts per million (PPM) equates to 2.5% of input clock period.
- (3) During device configuration, the ClockLock and ClockBoost circuitry is configured before the rest of the device. If the incoming clock is supplied during configuration, the ClockLock and ClockBoost circuitry locks during configuration because the  $t_{LOCK}$  value is less than the time required for configuration.
- (4) The  $t_{JITTER}$  specification is measured under long-term observation. The maximum value for  $t_{JITTER}$  is 200 ps if  $t_{INCLKSTB}$  is lower than 50 ps.

## I/O Configuration

This section discusses the peripheral component interconnect (PCI) pull-up clamping diode option, slew-rate control, open-drain output option, and MultiVolt I/O interface for FLEX 10KE devices. The PCI pull-up clamping diode, slew-rate control, and open-drain output options are controlled pin-by-pin via Altera software logic options. The MultiVolt I/O interface is controlled by connecting  $V_{CCIO}$  to a different voltage than  $V_{CCINT}$ . Its effect can be simulated in the Altera software via the **Global Project Device Options** dialog box (Assign menu).



*Table 17. 32-Bit IDCODE for FLEX 10KE Devices* *Note (1)*

Device	IDCODE (32 Bits)			
	Version (4 Bits)	Part Number (16 Bits)	Manufacturer's Identity (11 Bits)	1 (1 Bit) (2)
EPF10K30E	0001	0001 0000 0011 0000	00001101110	1
EPF10K50E EPF10K50S	0001	0001 0000 0101 0000	00001101110	1
EPF10K100E	0010	0000 0001 0000 0000	00001101110	1
EPF10K130E	0001	0000 0001 0011 0000	00001101110	1
EPF10K200E EPF10K200S	0001	0000 0010 0000 0000	00001101110	1

**Notes:**

- (1) The most significant bit (MSB) is on the left.  
 (2) The least significant bit (LSB) for all JTAG IDCODEs is 1.

FLEX 10KE devices include weak pull-up resistors on the JTAG pins.



For more information, see the following documents:

- *Application Note 39 (IEEE Std. 1149.1 (JTAG) Boundary-Scan Testing in Altera Devices)*
- *BitBlaster Serial Download Cable Data Sheet*
- *ByteBlasterMV Parallel Port Download Cable Data Sheet*
- *Jam Programming & Test Language Specification*

Figure 25. FLEX 10KE Device LE Timing Model

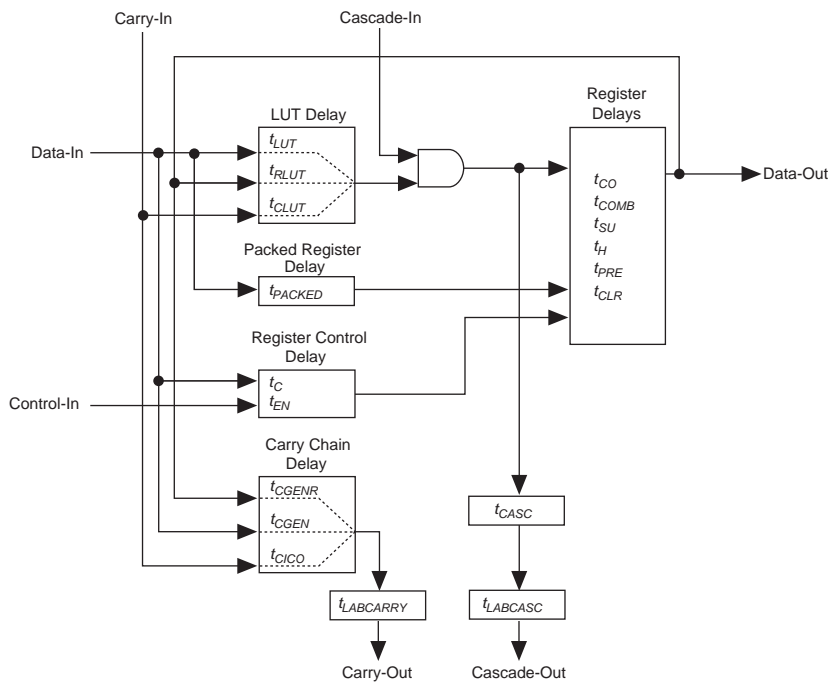


Figure 26. FLEX 10KE Device IOE Timing Model

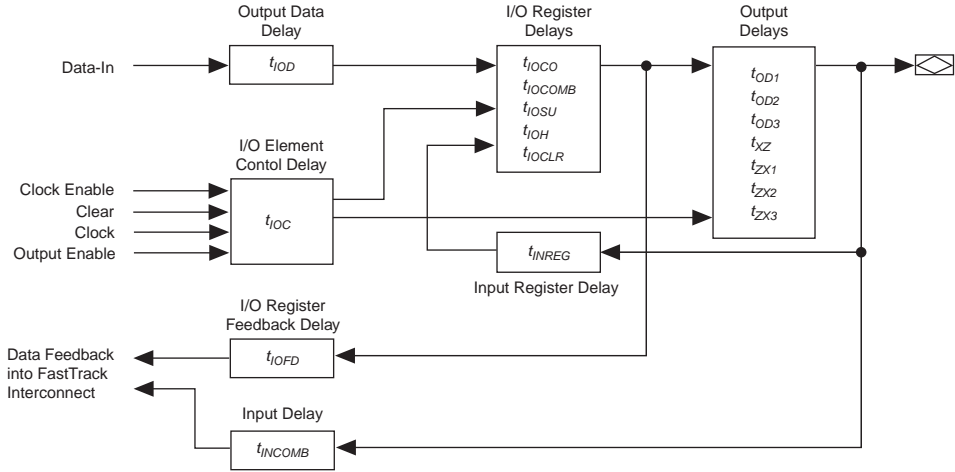


Figure 27. FLEX 10KE Device EAB Timing Model

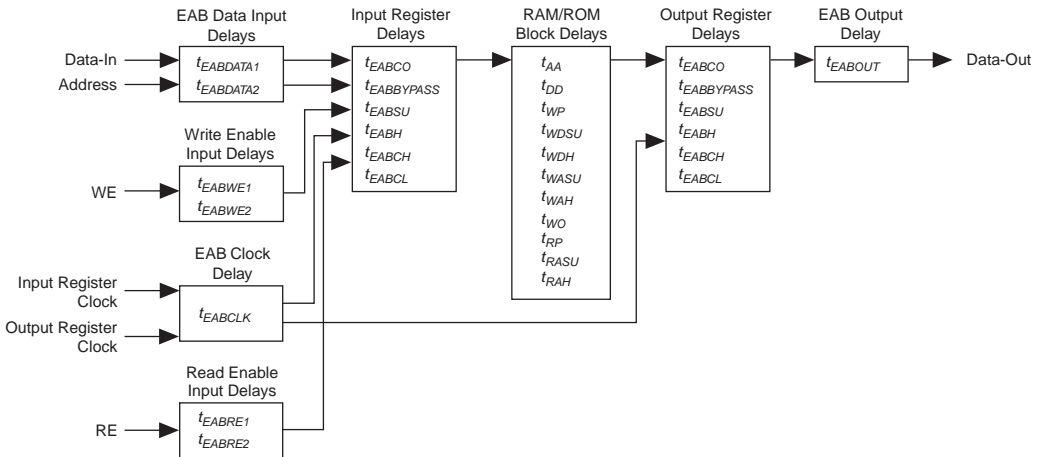


Table 28. Interconnect Timing Microparameters *Note (1)*

Symbol	Parameter	Conditions
$t_{DIN2IOE}$	Delay from dedicated input pin to IOE control input	(7)
$t_{DIN2LE}$	Delay from dedicated input pin to LE or EAB control input	(7)
$t_{DCLK2IOE}$	Delay from dedicated clock pin to IOE clock	(7)
$t_{DCLK2LE}$	Delay from dedicated clock pin to LE or EAB clock	(7)
$t_{DIN2DATA}$	Delay from dedicated input or clock to LE or EAB data	(7)
$t_{SAMELAB}$	Routing delay for an LE driving another LE in the same LAB	
$t_{SAMEROW}$	Routing delay for a row IOE, LE, or EAB driving a row IOE, LE, or EAB in the same row	(7)
$t_{SAMECOLUMN}$	Routing delay for an LE driving an IOE in the same column	(7)
$t_{DIFFROW}$	Routing delay for a column IOE, LE, or EAB driving an LE or EAB in a different row	(7)
$t_{TROWROWS}$	Routing delay for a row IOE or EAB driving an LE or EAB in a different row	(7)
$t_{LEPERIPH}$	Routing delay for an LE driving a control signal of an IOE via the peripheral control bus	(7)
$t_{LABCARRY}$	Routing delay for the carry-out signal of an LE driving the carry-in signal of a different LE in a different LAB	
$t_{LABCASC}$	Routing delay for the cascade-out signal of an LE driving the cascade-in signal of a different LE in a different LAB	

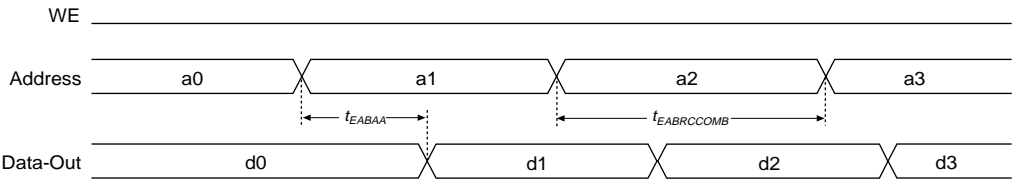
Table 29. External Timing Parameters

Symbol	Parameter	Conditions
$t_{DRR}$	Register-to-register delay via four LEs, three row interconnects, and four local interconnects	(8)
$t_{INSU}$	Setup time with global clock at IOE register	(9)
$t_{INH}$	Hold time with global clock at IOE register	(9)
$t_{OUTCO}$	Clock-to-output delay with global clock at IOE register	(9)
$t_{PCISU}$	Setup time with global clock for registers used in PCI designs	(9),(10)
$t_{PCIH}$	Hold time with global clock for registers used in PCI designs	(9),(10)
$t_{PCICO}$	Clock-to-output delay with global clock for registers used in PCI designs	(9),(10)

Figures 29 and 30 show the asynchronous and synchronous timing waveforms, respectively, or the EAB macroparameters in Tables 26 and 27.

Figure 29. EAB Asynchronous Timing Waveforms

EAB Asynchronous Read



EAB Asynchronous Write

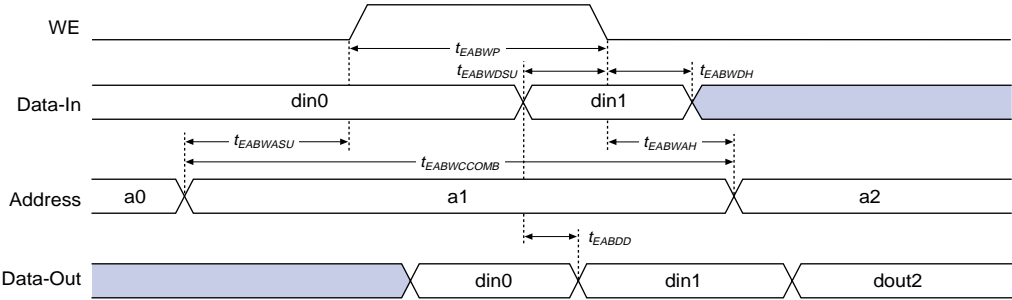


Table 34. EPF10K30E Device EAB Internal Timing Macroparameters *Note (1)*

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{EABAA}$		6.4		7.6		8.8	ns
$t_{EABRCOMB}$	6.4		7.6		8.8		ns
$t_{EABRCREG}$	4.4		5.1		6.0		ns
$t_{EABWP}$	2.5		2.9		3.3		ns
$t_{EABWCOMB}$	6.0		7.0		8.0		ns
$t_{EABWCREG}$	6.8		7.8		9.0		ns
$t_{EABDD}$		5.7		6.7		7.7	ns
$t_{EABDATACO}$		0.8		0.9		1.1	ns
$t_{EABDATASU}$	1.5		1.7		2.0		ns
$t_{EABDATAH}$	0.0		0.0		0.0		ns
$t_{EABWESU}$	1.3		1.4		1.7		ns
$t_{EABWEH}$	0.0		0.0		0.0		ns
$t_{EABWDSU}$	1.5		1.7		2.0		ns
$t_{EABWDH}$	0.0		0.0		0.0		ns
$t_{EABWASU}$	3.0		3.6		4.3		ns
$t_{EABWAH}$	0.5		0.5		0.4		ns
$t_{EABWO}$		5.1		6.0		6.8	ns

Table 47. EPF10K100E Device EAB Internal Microparameters *Note (1)*

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{EABDATA1}$		1.5		2.0		2.6	ns
$t_{EABDATA1}$		0.0		0.0		0.0	ns
$t_{EABWE1}$		1.5		2.0		2.6	ns
$t_{EABWE2}$		0.3		0.4		0.5	ns
$t_{EABRE1}$		0.3		0.4		0.5	ns
$t_{EABRE2}$		0.0		0.0		0.0	ns
$t_{EABCLK}$		0.0		0.0		0.0	ns
$t_{EABCO}$		0.3		0.4		0.5	ns
$t_{EABYPASS}$		0.1		0.1		0.2	ns
$t_{EABSU}$	0.8		1.0		1.4		ns
$t_{EABH}$	0.1		0.1		0.2		ns
$t_{EABCLR}$	0.3		0.4		0.5		ns
$t_{AA}$		4.0		5.1		6.6	ns
$t_{WP}$	2.7		3.5		4.7		ns
$t_{RP}$	1.0		1.3		1.7		ns
$t_{WDSU}$	1.0		1.3		1.7		ns
$t_{WDH}$	0.2		0.2		0.3		ns
$t_{WASU}$	1.6		2.1		2.8		ns
$t_{WAH}$	1.6		2.1		2.8		ns
$t_{RASU}$	3.0		3.9		5.2		ns
$t_{RAH}$	0.1		0.1		0.2		ns
$t_{WO}$		1.5		2.0		2.6	ns
$t_{DD}$		1.5		2.0		2.6	ns
$t_{EABOUT}$		0.2		0.3		0.3	ns
$t_{EABCH}$	1.5		2.0		2.5		ns
$t_{EABCL}$	2.7		3.5		4.7		ns

Table 48. EPF10K100E Device EAB Internal Timing Macroparameters (Part 1 of 2) *Note (1)*

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{EABAA}$		5.9		7.6		9.9	ns
$t_{EABRCOMB}$	5.9		7.6		9.9		ns
$t_{EABRCREG}$	5.1		6.5		8.5		ns
$t_{EABWP}$	2.7		3.5		4.7		ns

Table 54. EPF10K130E Device EAB Internal Microparameters (Part 2 of 2) *Note (1)*

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{DD}$		1.5		2.0		2.6	ns
$t_{EABOUT}$		0.2		0.3		0.3	ns
$t_{EABCH}$	1.5		2.0		2.5		ns
$t_{EABCL}$	2.7		3.5		4.7		ns

Table 55. EPF10K130E Device EAB Internal Timing Macroparameters *Note (1)*

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{EABAA}$		5.9		7.5		9.9	ns
$t_{EABRCOMB}$	5.9		7.5		9.9		ns
$t_{EABRCREG}$	5.1		6.4		8.5		ns
$t_{EABWP}$	2.7		3.5		4.7		ns
$t_{EABWCOMB}$	5.9		7.7		10.3		ns
$t_{EABWCREG}$	5.4		7.0		9.4		ns
$t_{EABDD}$		3.4		4.5		5.9	ns
$t_{EABDATAO}$		0.5		0.7		0.8	ns
$t_{EABDATASU}$	0.8		1.0		1.4		ns
$t_{EABDATAH}$	0.1		0.1		0.2		ns
$t_{EABWESU}$	1.1		1.4		1.9		ns
$t_{EABWEH}$	0.0		0.0		0.0		ns
$t_{EABWDSU}$	1.0		1.3		1.7		ns
$t_{EABWDH}$	0.2		0.2		0.3		ns
$t_{EABWASU}$	4.1		5.1		6.8		ns
$t_{EABWAH}$	0.0		0.0		0.0		ns
$t_{EABWO}$		3.4		4.5		5.9	ns



Table 66. EPF10K50S Device LE Timing Microparameters (Part 2 of 2) *Note (1)*

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{CGENR}$		0.1		0.1		0.1	ns
$t_{CASC}$		0.5		0.8		1.0	ns
$t_C$		0.5		0.6		0.8	ns
$t_{CO}$		0.6		0.6		0.7	ns
$t_{COMB}$		0.3		0.4		0.5	ns
$t_{SU}$	0.5		0.6		0.7		ns
$t_H$	0.5		0.6		0.8		ns
$t_{PRE}$		0.4		0.5		0.7	ns
$t_{CLR}$		0.8		1.0		1.2	ns
$t_{CH}$	2.0		2.5		3.0		ns
$t_{CL}$	2.0		2.5		3.0		ns

Table 67. EPF10K50S Device IOE Timing Microparameters *Note (1)*

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{IOD}$		1.3		1.3		1.9	ns
$t_{IOC}$		0.3		0.4		0.4	ns
$t_{IOCO}$		1.7		2.1		2.6	ns
$t_{IOCOMB}$		0.5		0.6		0.8	ns
$t_{IOSU}$	0.8		1.0		1.3		ns
$t_{IOH}$	0.4		0.5		0.6		ns
$t_{IOCLR}$		0.2		0.2		0.4	ns
$t_{OD1}$		1.2		1.2		1.9	ns
$t_{OD2}$		0.7		0.8		1.7	ns
$t_{OD3}$		2.7		3.0		4.3	ns
$t_{XZ}$		4.7		5.7		7.5	ns
$t_{ZX1}$		4.7		5.7		7.5	ns
$t_{ZX2}$		4.2		5.3		7.3	ns
$t_{ZX3}$		6.2		7.5		9.9	ns
$t_{INREG}$		3.5		4.2		5.6	ns
$t_{IOFD}$		1.1		1.3		1.8	ns
$t_{INCOMB}$		1.1		1.3		1.8	ns

Table 68. EPF10K50S Device EAB Internal Microparameters *Note (1)*

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{EABDATA1}$		1.7		2.4		3.2	ns
$t_{EABDATA2}$		0.4		0.6		0.8	ns
$t_{EABWE1}$		1.0		1.4		1.9	ns
$t_{EABWE2}$		0.0		0.0		0.0	ns
$t_{EABRE1}$		0.0		0.0		0.0	
$t_{EABRE2}$		0.4		0.6		0.8	
$t_{EABCLK}$		0.0		0.0		0.0	ns
$t_{EABCO}$		0.8		1.1		1.5	ns
$t_{EABYPASS}$		0.0		0.0		0.0	ns
$t_{EABSU}$	0.7		1.0		1.3		ns
$t_{EABH}$	0.4		0.6		0.8		ns
$t_{EABCLR}$	0.8		1.1		1.5		
$t_{AA}$		2.0		2.8		3.8	ns
$t_{WP}$	2.0		2.8		3.8		ns
$t_{RP}$	1.0		1.4		1.9		
$t_{WDSU}$	0.5		0.7		0.9		ns
$t_{WDH}$	0.1		0.1		0.2		ns
$t_{WASU}$	1.0		1.4		1.9		ns
$t_{WAH}$	1.5		2.1		2.9		ns
$t_{RASU}$	1.5		2.1		2.8		
$t_{RAH}$	0.1		0.1		0.2		
$t_{WO}$		2.1		2.9		4.0	ns
$t_{DD}$		2.1		2.9		4.0	ns
$t_{EABOUT}$		0.0		0.0		0.0	ns
$t_{EABCH}$	1.5		2.0		2.5		ns
$t_{EABCL}$	1.5		2.0		2.5		ns

Table 76. EPF10K200S Device EAB Internal Timing Macroparameters *Note (1)*

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{EABAA}$		3.9		6.4		8.4	ns
$t_{EABRCOMB}$	3.9		6.4		8.4		ns
$t_{EABRCREG}$	3.6		5.7		7.6		ns
$t_{EABWP}$	2.1		4.0		5.3		ns
$t_{EABWCOMB}$	4.8		8.1		10.7		ns
$t_{EABWCREG}$	5.4		8.0		10.6		ns
$t_{EABDD}$		3.8		5.1		6.7	ns
$t_{EABDATAO}$		0.8		1.0		1.3	ns
$t_{EABDATASU}$	1.1		1.6		2.1		ns
$t_{EABDATAH}$	0.0		0.0		0.0		ns
$t_{EABWESU}$	0.7		1.1		1.5		ns
$t_{EABWEH}$	0.4		0.5		0.6		ns
$t_{EABWDSU}$	1.2		1.8		2.4		ns
$t_{EABWDH}$	0.0		0.0		0.0		ns
$t_{EABWASU}$	1.9		3.6		4.7		ns
$t_{EABWAH}$	0.8		0.5		0.7		ns
$t_{EABWO}$		3.1		4.4		5.8	ns

Table 77. EPF10K200S Device Interconnect Timing Microparameters (Part 1 of 2) *Note (1)*

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{DIN2IOE}$		4.4		4.8		5.5	ns
$t_{DIN2LE}$		0.6		0.6		0.9	ns
$t_{DIN2DATA}$		1.8		2.1		2.8	ns
$t_{DCLK2IOE}$		1.7		2.0		2.8	ns
$t_{DCLK2LE}$		0.6		0.6		0.9	ns
$t_{SAMELAB}$		0.1		0.1		0.2	ns
$t_{SAMEROW}$		3.0		4.6		5.7	ns
$t_{SAMECOLUMN}$		3.5		4.9		6.4	ns
$t_{DIFFROW}$		6.5		9.5		12.1	ns
$t_{TWOROWS}$		9.5		14.1		17.8	ns
$t_{LEPERIPH}$		5.5		6.2		7.2	ns
$t_{LABCARRY}$		0.3		0.1		0.2	ns

# Power Consumption

The supply power (P) for FLEX 10KE devices can be calculated with the following equation:

$$P = P_{INT} + P_{IO} = (I_{CCSTANDBY} + I_{CCACTIVE}) \times V_{CC} + P_{IO}$$

The  $I_{CCACTIVE}$  value depends on the switching frequency and the application logic. This value is calculated based on the amount of current that each LE typically consumes. The  $P_{IO}$  value, which depends on the device output load characteristics and switching frequency, can be calculated using the guidelines given in [Application Note 74 \(Evaluating Power for Altera Devices\)](#).

Compared to the rest of the device, the embedded array consumes a negligible amount of power. Therefore, the embedded array can be ignored when calculating supply current.

The  $I_{CCACTIVE}$  value can be calculated with the following equation:

$$I_{CCACTIVE} = K \times f_{MAX} \times N \times \text{tog}_{LC} \times \frac{\mu A}{MHz \times LE}$$

Where:

- $f_{MAX}$  = Maximum operating frequency in MHz
- $N$  = Total number of LEs used in the device
- $\text{tog}_{LC}$  = Average percent of LEs toggling at each clock (typically 12.5%)
- $K$  = Constant

**Table 80** provides the constant (K) values for FLEX 10KE devices.

Table 80. FLEX 10KE K Constant Values	
Device	K Value
EPF10K30E	4.5
EPF10K50E	4.8
EPF10K50S	4.5
EPF10K100E	4.5
EPF10K130E	4.6
EPF10K200E	4.8
EPF10K200S	4.6

This calculation provides an  $I_{CC}$  estimate based on typical conditions with no output load. The actual  $I_{CC}$  should be verified during operation because this measurement is sensitive to the actual pattern in the device and the environmental operating conditions.



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